

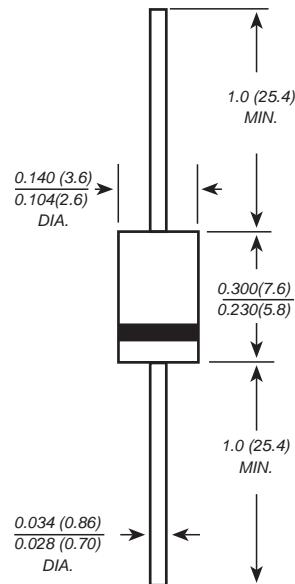


GENERAL PURPOSE SILICON RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Construction utilizes void-free molded plastic technique
- Low reverse leakage
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
- ◆ 250°C/10 seconds, 0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension

DO-15

ROHS
COMPLIANT**Mechanical Data****Case :** JEDEC DO-15 Molded plastic body**Terminals :** Solder plated, solderable per MIL-STD-750, Method 2026**Polarity :** Polarity symbol marking on body**Mounting Position :** Any**Weight :** 0.014 ounce, 0.40 grams

Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	RL201	RL202	RL203	RL204	RL205	RL206	RL207	UNITS
		MDD RL201	MDD RL202	MDD RL203	MDD RL204	MDD RL205	MDD RL206	MDD RL207	
Marking Code									
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at TA=75°C	I _(AV)	2.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	70.0							A
Maximum instantaneous forward voltage at 2.0A	V _F	1.1							V
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=100°C	I _R	5.0 50.0							µA
Typical junction capacitance (NOTE 1)	C _J	20.0							pF
Typical thermal resistance (NOTE 2)	R _{θ JA}	50.0							°C/W
Operating junction and storage temperature range	T _{J,T_{STG}}	-50 to +150							°C

Note:1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

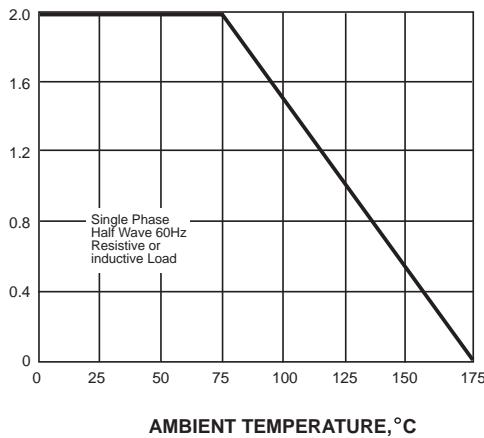
2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length,P.C.B. mounted



Ratings And Characteristic Curves

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

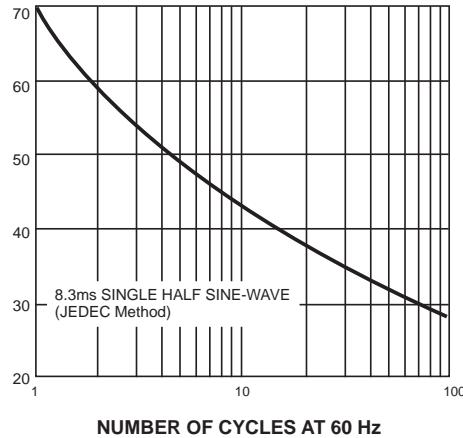
FIG. 1- FORWARD CURRENT DERATING CURVE



AMBIENT TEMPERATURE, °C

PEAK FORWARD SURGE CURRENT,
AMPERES

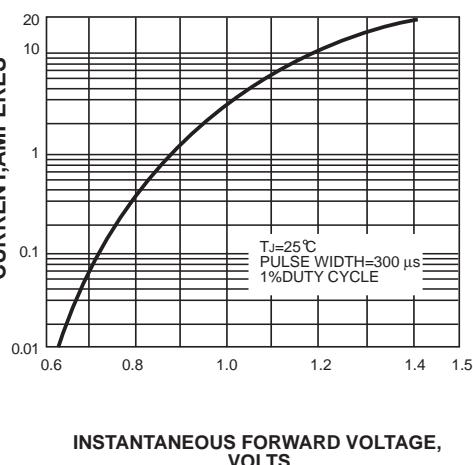
FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz

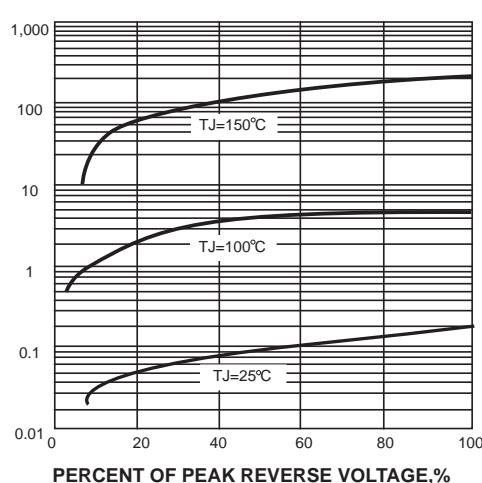
INSTANTANEOUS FORWARD
CURRENT,AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

INSTANTANEOUS FORWARD VOLTAGE,
VOLTS

INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES

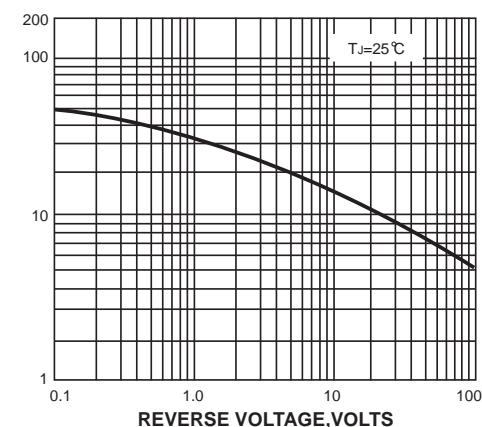
FIG. 4-TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE, %

JUNCTION CAPACITANCE, pF

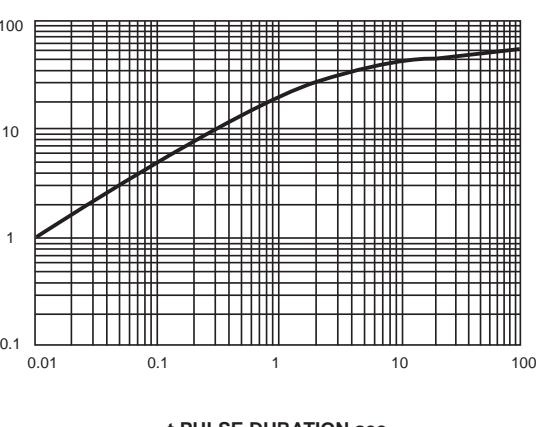
FIG. 5-TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



t,PULSE DURATION,sec.

The curve above is for reference only.

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